NSN 5961-01-480-6827

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-480-6827 **Inclosure Material:** Ceramic **Overall Length:** 10.540 millimeters **Terminal Length:** 5.080 millimeters **Overall Height:** 29.330 millimeters **Overall Width:** 2.890 millimeters **Mounting Facility Quantity: Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 150.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 620.00 amperes forward current, average **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction and -55.0 degrees celsius junction **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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